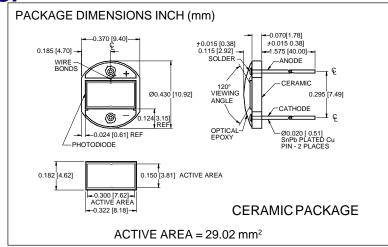
PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive Type PDB-C140 DETECTORS INC.





FEATURES

- High speed
- Low capacitance
- Blue enhanced
- Low dark current

DESCRIPTION

The PDB-C140 is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged on a two lead ceramic substrate with a clear epoxy glob top.

APPLICATIONS

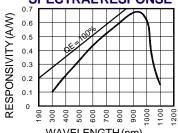
- Bar code scanner
- Instrumentation
- Industrial controls
- Laser detection

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	
V _{BR}	Reverse Voltage		100	V	
T _{STG}	Storage Temperature	-40	+100	∘C	
То	Operating Temperature Range	-40	+100	∘C	
Ts	Soldering Temperature*		+240	∘C	
I _L	Light Current		0.5	mA	

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



WAVELENGTH (nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
I _{sc}	Short Circuit Current	H = 100 fc, 2850 K	350	400		μΑ
I _D	Dark Current	$H = 0, V_R = 10 V$		10	25	nA
Rsh	Shunt Resistance	H = 0, V _R = 10 mV	5	50		MΩ
TC Rsh	RSH Temp. Coefficient	H = 0, V _R = 10 mV		-8		%/℃
Сл	Junction Capacitance	H = 0, V _R = 10 V**		200		pF
λrange	Spectral Application Range	Spot Scan	350		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
VBR	Breakdown Voltage	I = 10 μA	50	75		V
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		9x10 ⁻¹³		W/ √ Hz
tr	Response Time	RL = 1 KΩ V _R = 50 V		18		nS